

### **FEATURES**

- Excellent character appearance.
- Case mold type.
- Touch pad.
- Black face (overlay) / White segment.
- RoHS compliant, Pb Free.

### **DESCRIPTION**

The CTD1010PG-PD-BW is a Touch Pad with 10.0 mm X 10.0 mm icon LED display.

This device utilizes Pure Green LED chip which are made from InGaN on a transparent GaN substrate.

The display has Black face (overlay), White segment.

This mold of display is attached with overlay.

### **DEVICE**

PART NO.	DESCRIPTION		
CTD1010PG-PD-BW	Touch pad with LED Display		

# **RoHS Compliance**

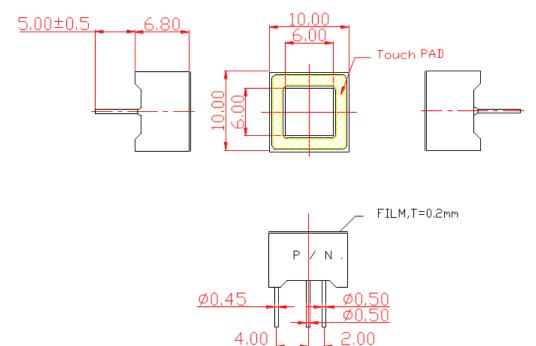


### Pb free.





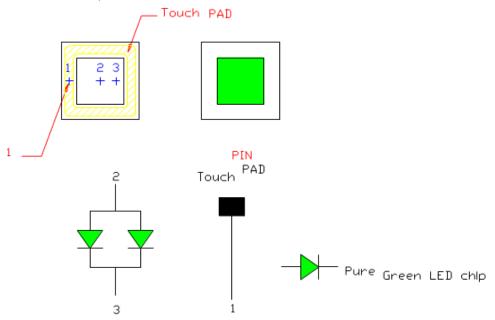
#### **MECHANICAL DIMENSIONS**



#### Notes:

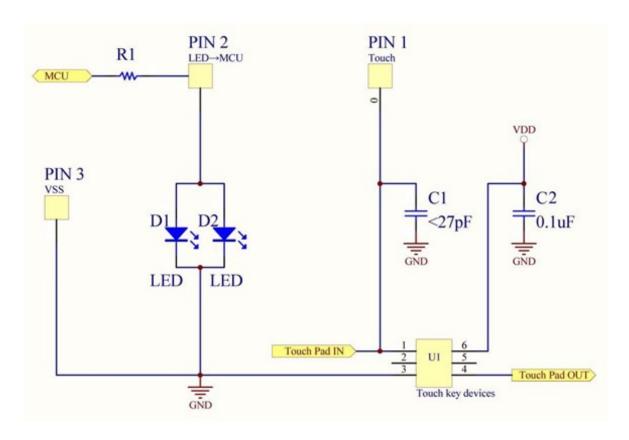
1. All dimensions are in millimeters (inches); tolerances are ±0.25mm (0.01") specified

### TYPICAL INTERNAL EQUIVALENT CIRCUIT





### **APPLICATION CIRCUITS**



INTERNAL COMPONENTS, NOT CUSTOMER ACCESSINLE.

#### **FILM**





## PG: PURE GREEN (InGaN/GaN)

### ABOSULTE MAXIMUM RATING AT Ta=25°C

Parameter	Symbol Maximum Rating		Unit	
Power dissipation per dice	P <sub>AD</sub>	120	mW	
Derating liner from 25°C per dice	-	0.3	mA / °C	
Continuous forward current per dice	I <sub>AF</sub>	30	mA	
Peak current (duty cycle 1/10, 1kHz)	<b>I</b> PF	100	mA	
Reverse voltage per dice	VR	5	V	
Operating temperature	Topr	-25 to +85	°C	
Storage temperature	Tstg	-25 to +85	°C	

### **ELECTRICAL-OPTICAL CHARACTERISTICS AT Ta=25°C**

Characteristic	Symbol	Condition	Min.	Type.	Max.	Unit
Forward Voltage	VF	I <sub>F</sub> =20mA	-	3.2	4.0	V
Reverse Current	I <sub>R</sub>	V <sub>R</sub> =8V	-	-	10	μΑ
Dominant Wavelength	$\lambda_{D}$	I <sub>F</sub> =20mA	-	525	-	nm
Average Luminous Intensity	Iv	I <sub>F</sub> =20mA	-	75	-	mcd
Spectral Radiation Bandwidth	Δλ	I <sub>F</sub> =20mA	-	30	-	nm



# PG: PURE GREEN (InGaN/GaN) CURVE TYPICAL ELECTRO-OPTICAL CHARACTERISTIC CURVE

#### Ta=25°C

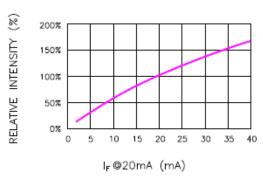


Fig.1 RELATIVE INTENSITY VS. FORWARD CURRENT

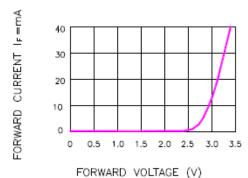
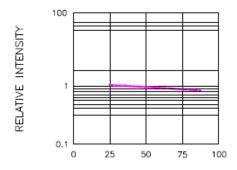
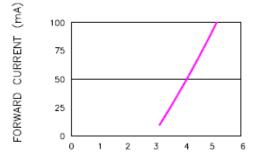


Fig.2 FORWARD CURRENT VS. FORWARD VOLTAGE



LEAD TEMPERATURE(\*C)
Fig.3 RELATIVE INTENSITY VS.LEAD TEMPERATURE

(PULSED 20 mA; 300us
PULSE,10ms PERIOD)



FORWARD VOLTAGE(V)
Fig.4 PEAK FORWARD VOLTAGE
VS.FORWARD(100us TEST PULSE,
1% DUTY CYCLE)

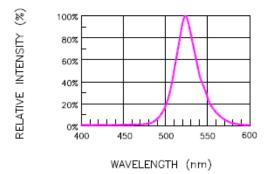


Fig.5 RELATIVE INTENSITY VS. WAVELENGTH

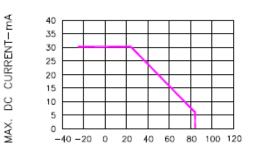
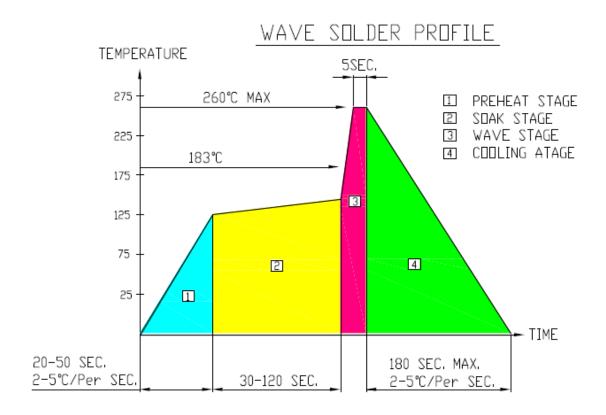


Fig.6 MAX. ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE

AMBIENT TEMPERATURE (TA)-\*C



#### RECOMMEND SOLDERING PROFILE



#### **NOTES**

- Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of 260°C
- 2. Peak wave soldering temperature between 245°C ~ 225°C for 3 sec (5 sec max)
- 3. No more than one wave soldering pass

### **SOLDERING IRON**

 Basic spec is ≤4 sec when 260°C. If temperature is higher, time should be shorter (+10°C→1 sec). Power dissipation of Iron should be smaller than 15W, and temperature should be controllable. Surface temperature of the device should be under 230°C

#### **REWORK**

- Customer must finish rework within 3 sec under 350°C
- 2. The head of soldering iron cannot touch copper foil